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0009911.9 20 April 2000 (20.04.2000) GB(71) Applicant (for all designated States except US): **PLASTIC LOGIC LIMITED** [GB/GB]; Sheraton House, Castle Park, Cambridge CB3 0AX (GB).

(72) Inventors; and

(75) Inventors/Applicants (for US only): **SIRRINGHAUS, Henning** [DE/GB]; Churchill College, Cambridge CB3 0DS (GB). **FRIEND, Richard, Henry** [GB/GB]; 37 Barton Road, Cambridge CB3 9LG (GB). **KAWASE, Takeo** [JP/GB]; 18 Eachard Road, Cambridge CB3 6HY (GB).(74) Agents: **SLINGSBY, Philip, Roy et al.**; Page White & Farrer, 54 Doughty Street, London WC1N 2LS (GB).

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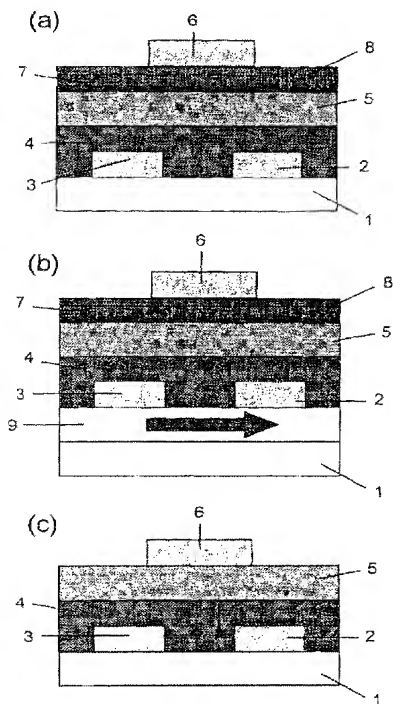
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(54) Title: SOLUTION PROCESSED DEVICES



(57) Abstract: A method for forming a transistor, comprising: depositing a first material from solution in a first solvent to form a first layer of the transistor; and subsequently whilst the first material remains soluble in the first solvent, forming a second layer of the transistor by depositing over the first material a second material from solution in a second solvent in which the first material is substantially insoluble.